Chipsmall Limited consists of a professional team with an average of over 10 year of expertise in the distribution of electronic components. Based in Hongkong, we have already established firm and mutual-benefit business relationships with customers from,Europe,America and south Asia,supplying obsolete and hard-to-find components to meet their specific needs.

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We are looking forward to setting up business relationship with you and hope to provide you with the best service and solution. Let us make a better world for our industry!

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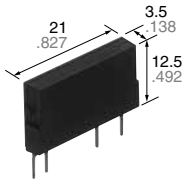
High capacity up to 6A in a slim SIL package

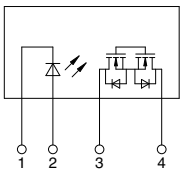
PhotoMOS®
Power 1 Form A
High Capacity (AQZ20○G)

New



(Height includes standoff)

mm inch



RoHS compliant

FEATURES

1. High capacity type power PhotoMOS.
Can switch a wide range of currents and voltages. Can control various types of loads, from very small loads to a max. 6A AC/DC current for sequencers, motors, and lamps.

2. Low on-resistance and high sensitivity.
Low on-resistance of less than typ. 0.015Ω (AQZ202G). High sensitivity LED operate current of typ. 1 mA.

3. AC/DC dual use
Bi-directional control is possible. There is no need to differentiate depending on the load as was necessary with the conventional SSR.

4. Slim SIL 4-pin package
(L) 21.0 mm × (W) 3.5 mm × (H) 12.5 mm (L) .827 inch × (W) .138 inch × (H) .492 inch
The compact size of the 4-pin SIL package allows high density mounting

5. Low-level off state leakage current of max. 10 μA

6. Controls low-level analog signals
The triac, photocoupler, or SSR cannot be used to control signals of less than several hundred mV. The high capacity type power PhotoMOS feature extremely low closed-circuit offset voltage to enable control of low-level analog signals without distortion.

TYPICAL APPLICATIONS

- Traffic signals
- Measuring instruments
- Industrial machines
- Mercury relay replacement

TYPES

	Output rating*		Package	Part No.	Packing quantity	
	Load voltage	Load current			Inner carton	Outer carton
AC/DC dual use	60 V	6.0 A	SIL4-pin	AQZ202G	25 pcs.	500 pcs.
	200 V	2.0 A		AQZ207G		

Note: Please refer to the "Cautions for use" regarding the recommended operation load voltage.
* Load voltage and current: Indicate the peak AC and DC values.

RATING

1. Absolute maximum ratings (Ambient temperature: 25°C 77°F)

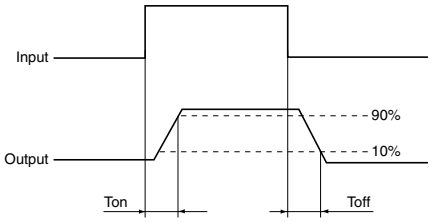
Item		Symbol	AQZ202G	AQZ207G	Remarks
Input	LED forward current	I_F	50 mA		
	LED reverse voltage	V_R	5 V		
	Peak forward current	I_{FP}	1 A		f = 100Hz, Duty factor = 0.1%
	Power dissipation	P_{in}	75 mW		
Output	Load voltage (peak AC)	V_L	60 V	200 V	
	Continuous load current	I_L	6.0 A	2.0 A	Peak AC, DC
	Peak load current	I_{peak}	12.0 A	6.0 A	100 ms (1shot), V_L = DC
	Power dissipation	P_{out}	1.6 W		
Total power dissipation		P_T	1.6 W		
I/O isolation voltage		V_{iso}	2,500 Vrms		
Temperature limits	Operating	T_{opr}	–40 to +85°C –40 to 185°F		(Non-icing at low temperatures)
	Storage	T_{stg}	–40 to +100°C –40 to 212°F		

2. Electrical characteristics (Ambient temperature: 25°C 77°F)

Item			Symbol	AQZ202G	AQZ207G	Condition
Input	LED operate current	Typical	I_{Fon}	1.0 mA		I_L = 100 mA V_L = 10 V
		Maximum		3.0 mA		
	LED turn off current	Minimum	I_{Foff}	0.2 mA		I_L = 100 mA V_L = 10 V
		Typical		0.9 mA		
	LED dropout voltage	Typical	V_F	1.25 V (1.16 V at I_F = 10 mA)		I_F = 50 mA
		Maximum		1.5 V		
Output	On resistance	Typical	R_{on}	0.015 Ω	0.18 Ω	I_F = 10 mA I_L = Max. Within 1 s on time
		Maximum		0.03 Ω	0.35 Ω	
	Off state leakage current	Maximum	I_{Leak}	10 μA		I_F = 0 mA V_L = Max.
Transfer characteristics	Turn on time*	Typical	T_{on}	3.8 ms	2.5 ms	I_F = 10 mA I_L = 100 mA V_L = 10 V
		Maximum		10 ms		
	Turn off time*	Typical	T_{off}	0.2 ms		I_F = 10 mA I_L = 100 mA V_L = 10 V
		Maximum		3.0 ms		
	I/O capacitance	Typical	C_{iso}	0.8 pF		f = 1 MHz V_B = 0 V
		Maximum		1.5 pF		
	Initial I/O isolation resistance	Minimum	R_{iso}	1,000 MΩ		500 V DC
	Maximum operating speed	Maximum	—	0.5 cps		I_F = 10 mA Duty factor = 50% I_L = Max., V_L = Max.

Note: Please refer to the “Schematic and Wiring Diagrams” for connection method.

*Turn on/Turn off time



3. Recommended operating conditions (Ambient temperature: 25°C 77°F)

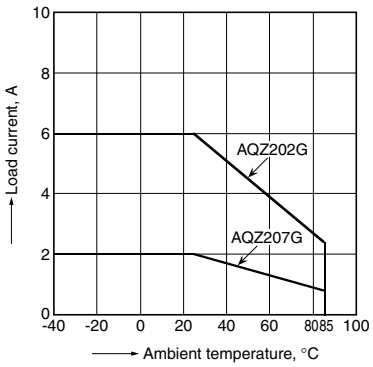
Please use under recommended operating conditions to obtain expected characteristics.

Item		Symbol	Min.	Max.	Unit
LED current		I_F	10	30	mA
AQZ202G	Load voltage (Peak AC)	V_L	—	48	V
	Continuous load current	I_L	—	6.0	A
AQZ207G	Load voltage (Peak AC)	V_L	—	160	V
	Continuous load current	I_L	—	2.0	A

REFERENCE DATA

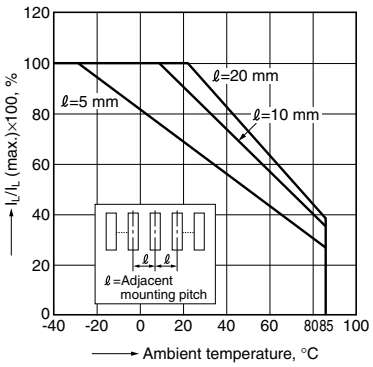
1. Load current vs. ambient temperature characteristics

Allowable ambient temperature: –40 to +85°C
–40 to +185°F



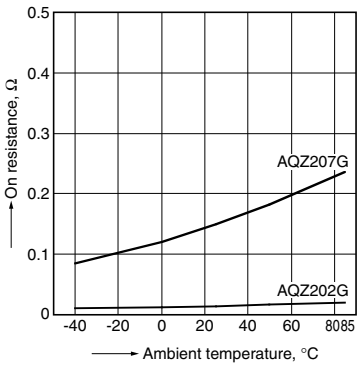
2. Load current vs. ambient temperature characteristics in adjacent mounting

I_L: Load current;
I_L (max.): Maximum continuous load current



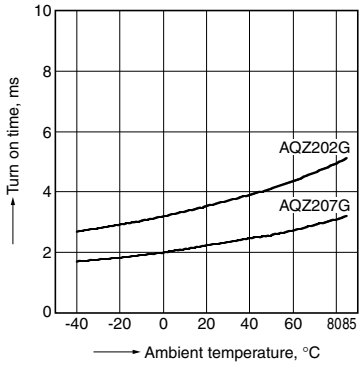
3. On resistance vs. ambient temperature characteristics

LED current: 10 mA;
Continuous load current: 6 A (DC) (AQZ202G),
2 A (DC) (AQZ207G)



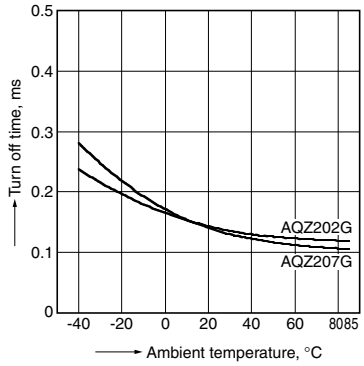
4. Turn on time vs. ambient temperature characteristics

LED current: 10 mA; Load voltage: 10 V (DC);
Continuous load current: 100 mA (DC)



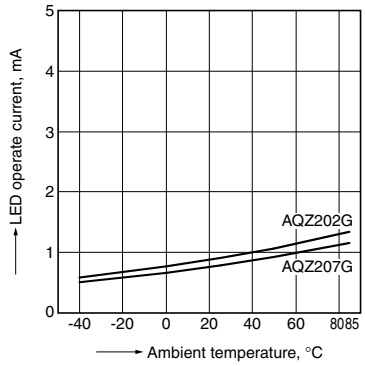
5. Turn off time vs. ambient temperature characteristics

LED current: 10 mA; Load voltage: 10 V (DC);
Continuous load current: 100 mA (DC)



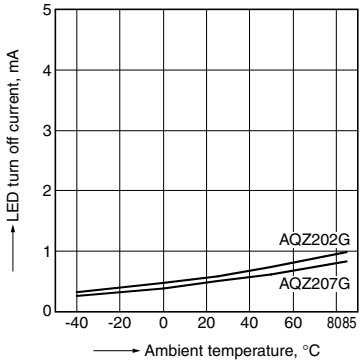
6. LED operate current vs. ambient temperature characteristics

Load voltage: 10 V (DC);
Continuous load current: 100 mA (DC)



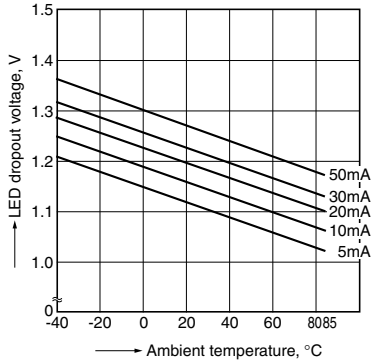
7. LED turn off current vs. ambient temperature characteristics

Load voltage: 10 V (DC);
Continuous load current: 100 mA (DC)



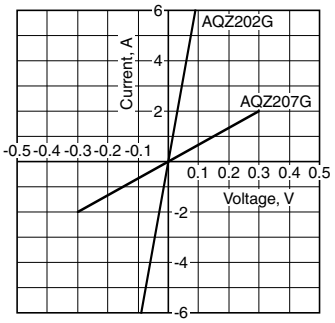
8. LED dropout voltage vs. ambient temperature characteristics

Sample: all types;
LED current: 5 to 50 mA



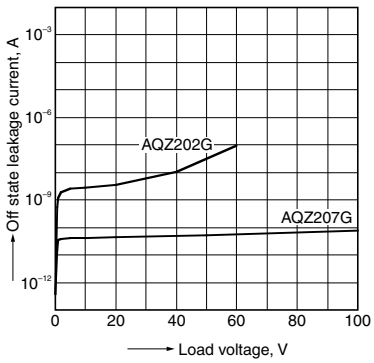
9. Current vs. voltage characteristics of output at MOS portion

Ambient temperature: 25°C 77°F



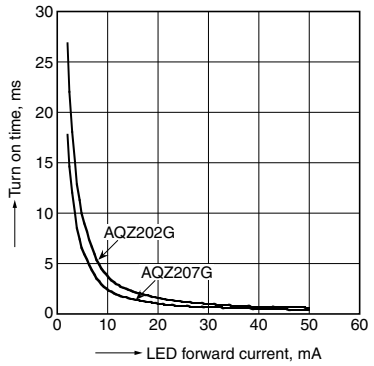
10. Off state leakage current vs. load voltage characteristics

Ambient temperature: 25°C 77°F



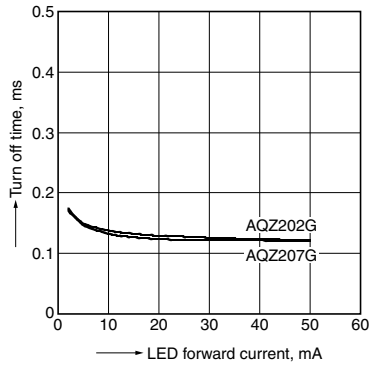
11. Turn on time vs. LED forward current characteristics

Load voltage: 10 V (DC);
Continuous load current: 100 mA (DC);
Ambient temperature: 25°C 77°F



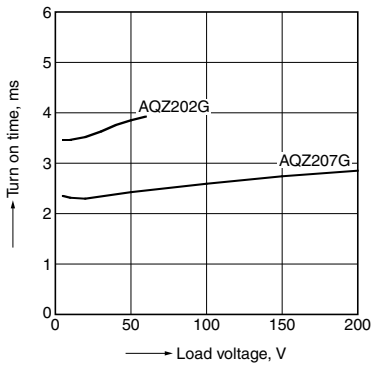
12. Turn off time vs. LED forward current characteristics

Load voltage: 10 V (DC);
Continuous load current: 100 mA (DC);
Ambient temperature: 25°C 77°F



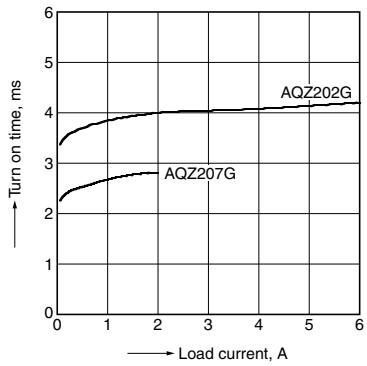
13. Turn on time vs. load voltage characteristics

LED current: 10 mA;
Continuous load current: 100 mA;
Ambient temperature: 25°C 77°F



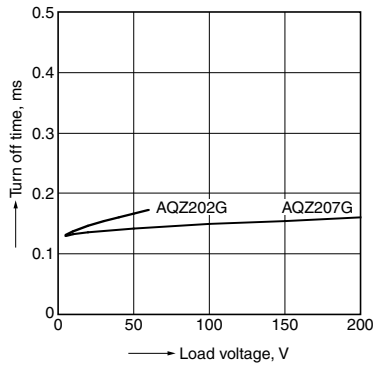
14. Turn on time vs. load current characteristics

LED current: 10 mA;
Load voltage: 10 V (DC);
Ambient temperature: 25°C 77°F



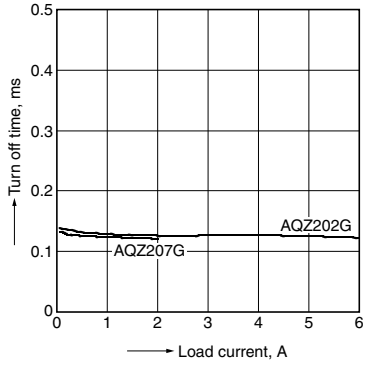
15. Turn off time vs. load voltage characteristics

LED current: 10 mA;
Continuous load current: 100 mA;
Ambient temperature: 25°C 77°F



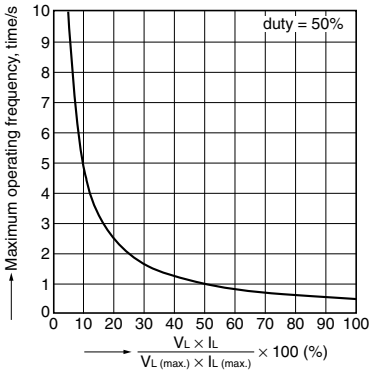
16. Turn off time vs. load current characteristics

LED current: 10 mA;
Load voltage: 10 V (DC);
Ambient temperature: 25°C 77°F



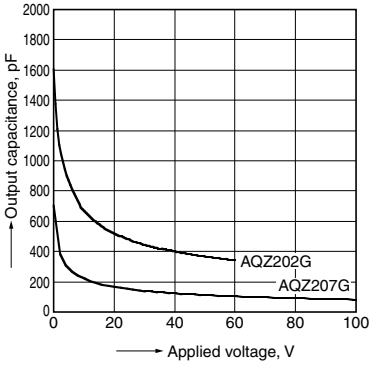
17. Maximum operating frequency vs. load voltage/current characteristics

Sample: All types; LED current: 10 mA;
Ambient temperature: 25°C 77°F
V_L: Load voltage, V_L (Max.): Max. rated load voltage
I_L: Load current, I_L (Max.): Max. rated continuous load current



18. Output capacitance vs. applied voltage characteristics

Frequency: 1 MHz;
Ambient temperature: 25°C 77°F



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